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FDMA86265P

P-Channel PowerTrench[®] MOSFET

-150 V, -1 A, 1.2 Ω

Features

- Max $r_{DS(on)}$ = 1.2 Ω at $V_{GS} = -10$ V, $I_D = -1$ A
- Max $r_{DS(on)}$ = 1.4 Ω at $V_{GS} = -6$ V, $I_D = -0.9$ A
- Low Profile - 0.8 mm maximum in the new package MicroFET 2x2 mm
- Very low RDS-on mid voltage P-channel silicon technology optimised for low Qg
- This product is optimised for fast switching applications as well as load switch applications
- 100% UIL tested
- RoHS Compliant

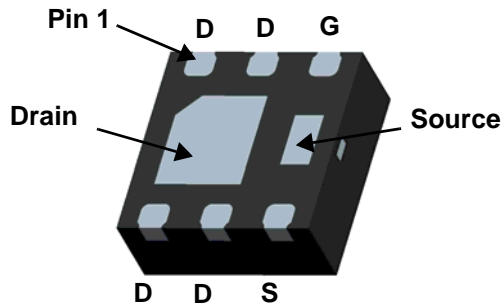


General Description

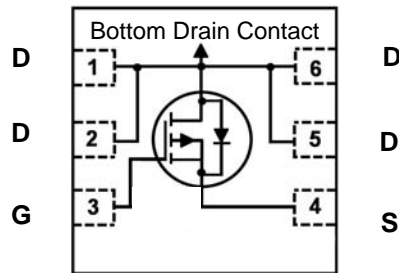
This P-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench[®] process that has been optimized for the on-state resistance and yet maintain superior switching performance.

Applications

- Active Clamp Switch
- Load Switch



MicroFET 2X2 (Bottom View)



MOSFET Maximum Ratings $T_A = 25$ °C unless otherwise noted

Symbol	Parameter	Rated	Units
V_{DS}	Drain to Source Voltage	-150	V
V_{GS}	Gate to Source Voltage	±25	V
I_D	Drain Current -Continuous	$T_A = 25$ °C (Note 1a)	-1
	-Pulsed		-2
E_{AS}	Single Pulse Avalanche Energy	(Note 3)	6
P_D	Power Dissipation	$T_A = 25$ °C (Note 1a)	2.4
	Power Dissipation	$T_A = 25$ °C (Note 1b)	0.9
T_J, T_{STG}	Operating and Storage Junction Temperature Range	-55 to + 150	°C

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	52	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	145	

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
265	FDMA86265P	MicroFET 2X2	7 "	12 mm	3000 units

Electrical Characteristics $T_J = 25\text{ }^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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Off Characteristics

BV_{DSS}	Drain to Source Breakdown Voltage	$I_D = -250\text{ }\mu\text{A}$, $V_{GS} = 0\text{ V}$	-150			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = -250\text{ }\mu\text{A}$, referenced to $25\text{ }^\circ\text{C}$		-125		mV/ $^\circ\text{C}$
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -120\text{ V}$, $V_{GS} = 0\text{ V}$			-1	μA
I_{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 25\text{ V}$, $V_{DS} = 0\text{ V}$			± 100	nA

On Characteristics

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = -250\text{ }\mu\text{A}$	-2	-3.2	-4	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = -250\text{ }\mu\text{A}$, referenced to $25\text{ }^\circ\text{C}$		5		mV/ $^\circ\text{C}$
$r_{DS(on)}$	Static Drain to Source On Resistance	$V_{GS} = -10\text{ V}$, $I_D = -1\text{ A}$		0.86	1.2	Ω
		$V_{GS} = -6\text{ V}$, $I_D = -0.9\text{ A}$		0.95	1.4	
		$V_{GS} = -10\text{ V}$, $I_D = -1\text{ A}$, $T_J = 125\text{ }^\circ\text{C}$		1.53	2.2	
g_{FS}	Forward Transconductance	$V_{DS} = -10\text{ V}$, $I_D = -1\text{ A}$		1.9		S

Dynamic Characteristics

C_{iss}	Input Capacitance	$V_{DS} = -75\text{ V}$, $V_{GS} = 0\text{ V}$, $f = 1\text{ MHz}$		158	210	pF
C_{oss}	Output Capacitance			16	25	pF
C_{rss}	Reverse Transfer Capacitance			0.7	5	pF
R_g	Gate Resistance		0.1	3	7.5	Ω

Switching Characteristics

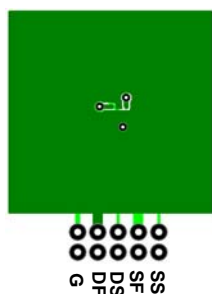
$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = -75\text{ V}$, $I_D = -1\text{ A}$, $V_{GS} = -10\text{ V}$, $R_{GEN} = 6\text{ }\Omega$		5.8	12	ns
t_r	Rise Time			2.2	10	ns
$t_{d(off)}$	Turn-Off Delay Time			8	16	ns
t_f	Fall Time			6.4	13	ns
$Q_{g(TOT)}$	Total Gate Charge		$V_{GS} = 0\text{ V to } -10\text{ V}$		2.8	4
Q_{gs}	Total Gate Charge	$I_D = -1\text{ A}$		0.8		nC
Q_{gd}	Gate to Drain "Miller" Charge			0.7		nC

Drain-Source Diode Characteristics

V_{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0\text{ V}$, $I_S = -1\text{ A}$ (Note 2)		-0.87	-1.3	V
t_{rr}	Reverse Recovery Time	$I_F = -1\text{ A}$, $di/dt = 100\text{ A}/\mu\text{s}$		50	80	ns
Q_{rr}	Reverse Recovery Charge			78	124	nC

NOTES:

- $R_{\theta JA}$ is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.



a. 52 $^\circ\text{C}/\text{W}$ when mounted on a 1 in² pad of 2 oz copper.



b. 145 $^\circ\text{C}/\text{W}$ when mounted on a minimum pad of 2 oz copper.

- Pulse Test: Pulse Width < 300 μs , Duty cycle < 2.0%.

- Starting $T_J = 25\text{ }^\circ\text{C}$; P-ch: L = 3 mH, $I_{AS} = -2\text{ A}$, $V_{DD} = -150\text{ V}$, $V_{GS} = -10\text{ V}$. 100% test at L = 0.1 mH, $I_{AS} = -9\text{ A}$.

Typical Characteristics $T_J = 25\text{ }^\circ\text{C}$ unless otherwise noted

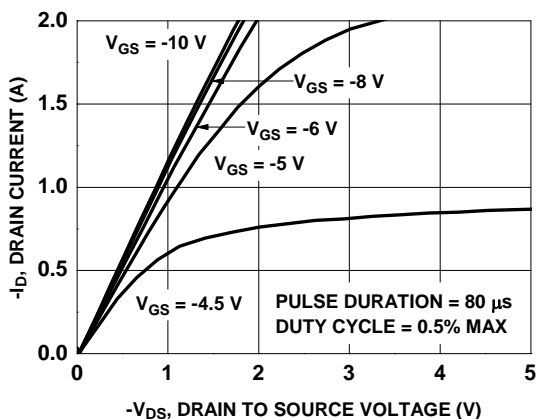


Figure 1. On Region Characteristics

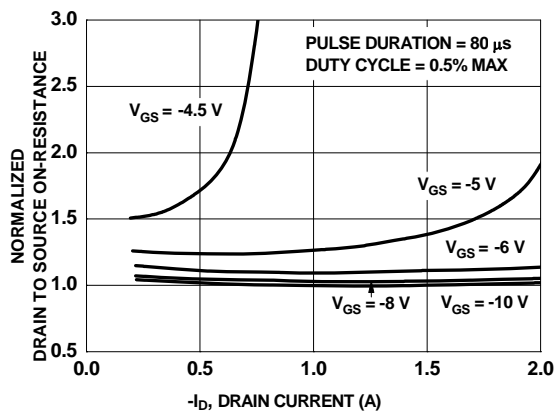


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

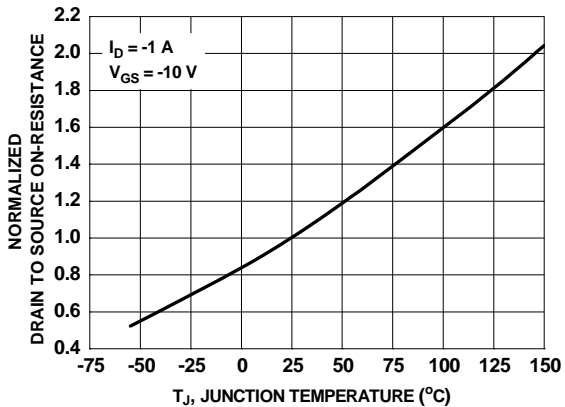


Figure 3. Normalized On Resistance vs Junction Temperature

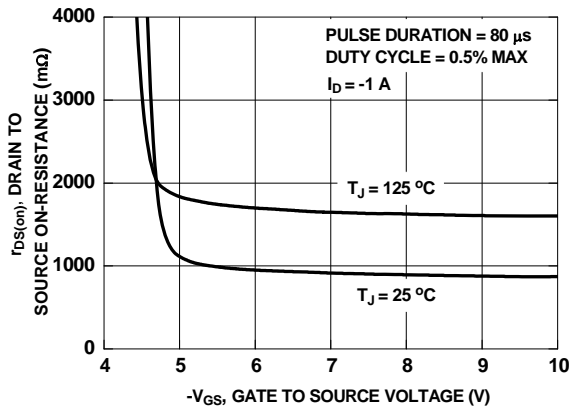


Figure 4. On-Resistance vs Gate to Source Voltage

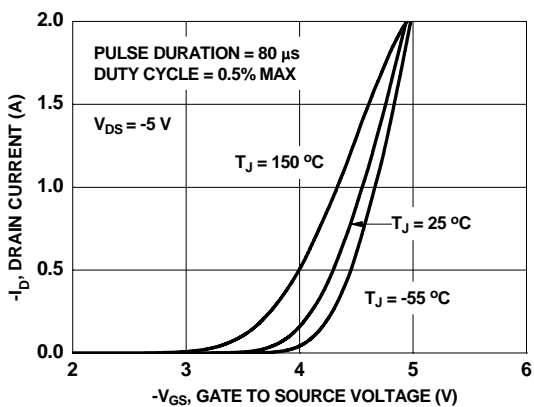


Figure 5. Transfer Characteristics

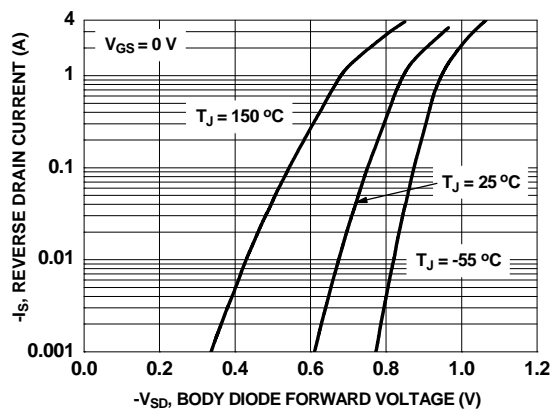


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

Typical Characteristics $T_J = 25\text{ }^\circ\text{C}$ unless otherwise noted

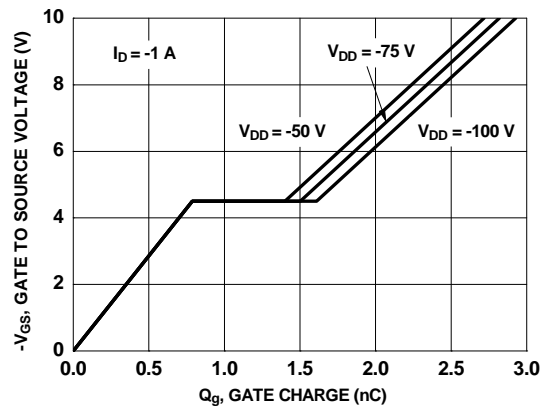


Figure 7. Gate Charge Characteristics

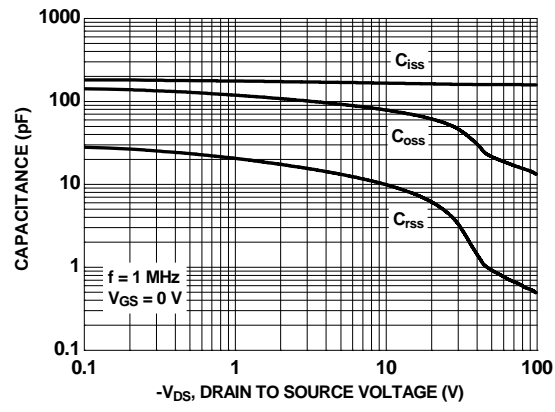


Figure 8. Capacitance vs Drain to Source Voltage

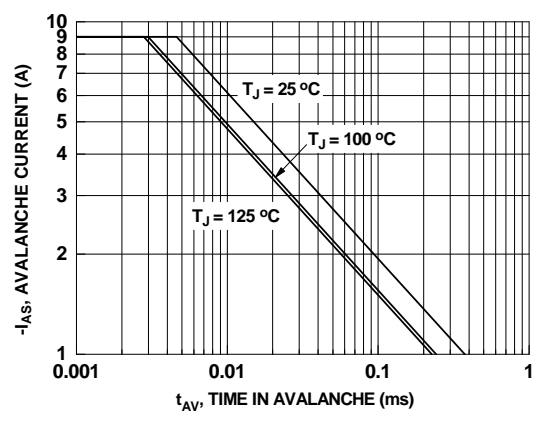


Figure 9. Unclamped Inductive Switching Capability

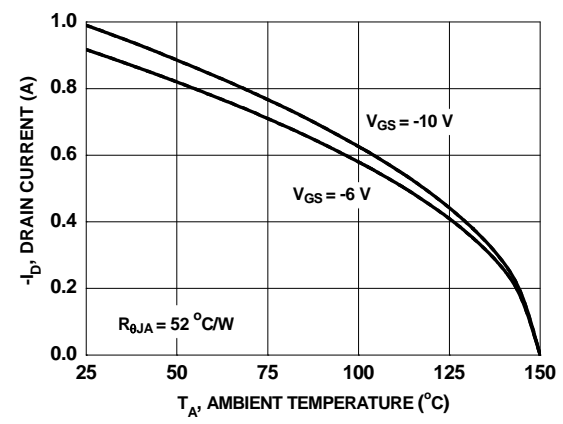


Figure 10. Maximum Continuous Drain Current vs Ambient Temperature

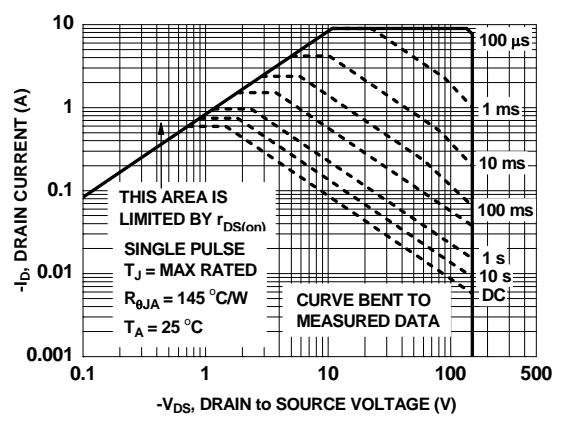


Figure 11. Forward Bias Safe Operating Area

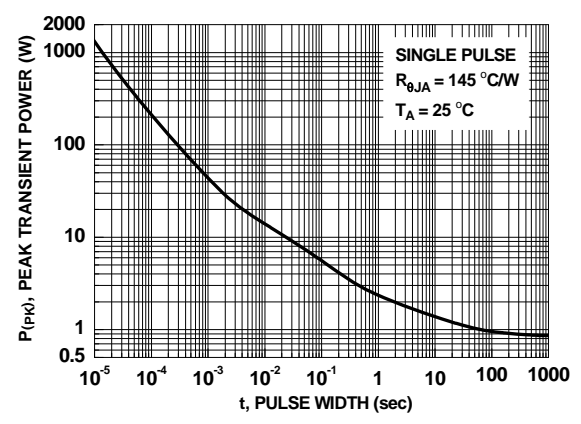


Figure 12. Single Pulse Maximum Power Dissipation

Typical Characteristics $T_J = 25\text{ }^\circ\text{C}$ unless otherwise noted

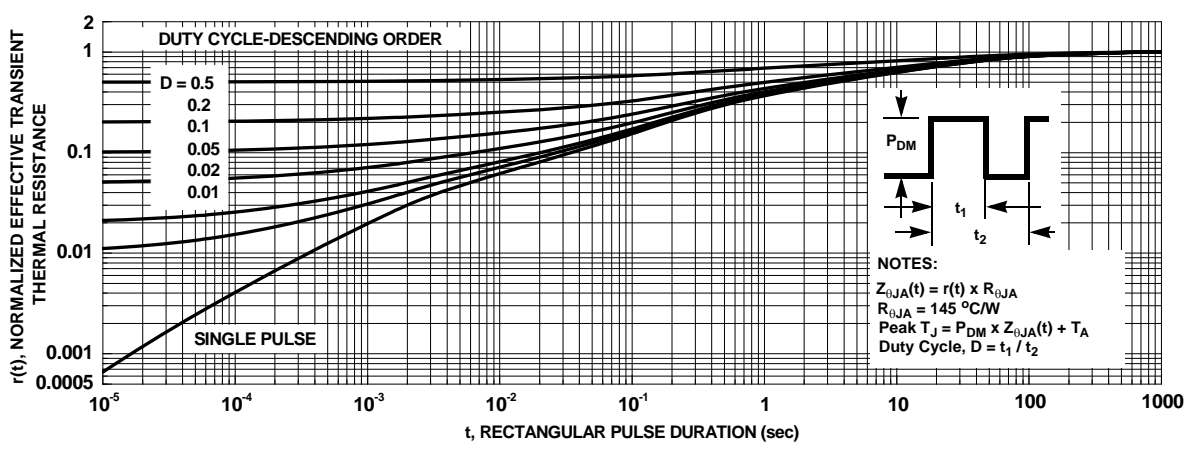
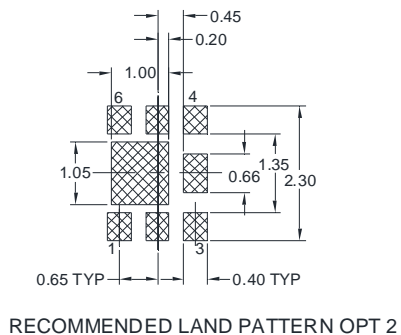
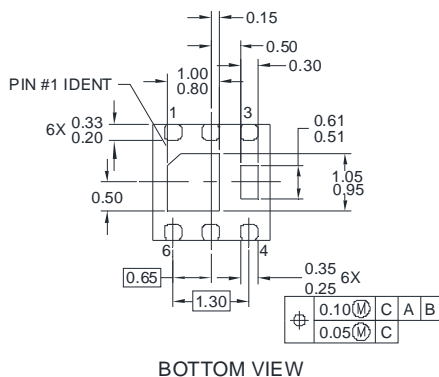
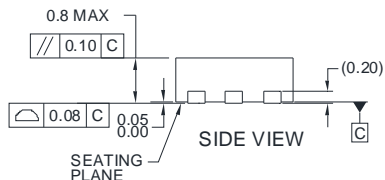
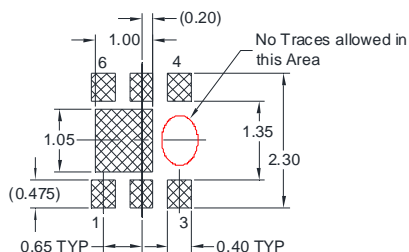
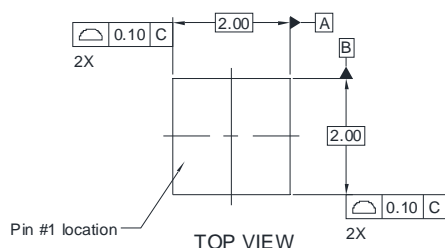


Figure 13. Junction-to-Ambient Transient Thermal Response Curve

Dimensional Outline and Pad Layout



NOTES:

- A. DOES NOT FULLY CONFORM TO JEDEC REGISTRATION MO-229 DATED AUG/2003
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994
- D. DRAWING FILENAME: MKT-MLP06Lrev3.





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